

# MSC2712GT1G, MSC2712YT1G

## General Purpose Amplifier Transistor

### NPN Surface Mount

#### Features

- Moisture Sensitivity Level: 1
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

#### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Rating	Symbol	Value	Unit
Collector-Base Voltage	$V_{(BR)CBO}$	60	Vdc
Collector-Emitter Voltage	$V_{(BR)CEO}$	50	Vdc
Emitter-Base Voltage	$V_{(BR)EBO}$	7.0	Vdc
Collector Current – Continuous	$I_C$	100	mAdc
Collector Current – Peak	$I_{C(P)}$	200	mAdc

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Power Dissipation	$P_D$	200	mW
Junction Temperature	$T_J$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



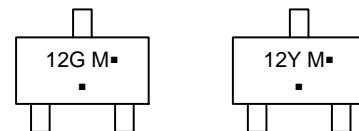
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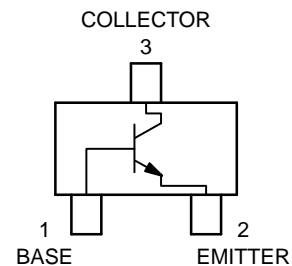


SC-59  
CASE 318D  
STYLE 1

#### MARKING DIAGRAMS



12M, 12Y = Specific Device Code  
M = Date Code  
▪ = Pb-Free Package  
(Note: Microdot may be in either location)



#### ORDERING INFORMATION

Device	Package	Shipping†
MSC2712GT1G	SC-59 (Pb-Free)	3000 / Tape & Reel
MSC2712YT1G	SC-59 (Pb-Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
Collector–Emitter Breakdown Voltage (I <sub>C</sub> = 2.0 mA, I <sub>B</sub> = 0)	V <sub>(BR)CEO</sub>	50	–	Vdc
Collector–Base Breakdown Voltage (I <sub>C</sub> = 10 μA, I <sub>E</sub> = 0)	V <sub>(BR)CBO</sub>	60	–	Vdc
Emitter–Base Breakdown Voltage (I <sub>E</sub> = 10 μA, I <sub>C</sub> = 0)	V <sub>(BR)EBO</sub>	7.0	–	Vdc
Collector–Base Cutoff Current (V <sub>CB</sub> = 45 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	–	0.1	μAdc
Collector–Emitter Cutoff Current (V <sub>CE</sub> = 10 Vdc, I <sub>B</sub> = 0) (V <sub>CE</sub> = 30 Vdc, I <sub>B</sub> = 0) (V <sub>CE</sub> = 30 Vdc, I <sub>B</sub> = 0, T <sub>A</sub> = 80°C)	I <sub>CEO</sub>	– – –	0.1 2.0 1.0	μAdc μAdc mAdc
DC Current Gain (Note 1) (V <sub>CE</sub> = 6.0 Vdc, I <sub>C</sub> = 2.0 mA)	h <sub>FE</sub>			–
		200 120	400 240	
Collector–Emitter Saturation Voltage (I <sub>C</sub> = 100 mA, I <sub>B</sub> = 10 mA)	V <sub>CE(sat)</sub>	–	0.5	Vdc
Current – Gain – Bandwidth Product (I <sub>C</sub> = 1 mA, V <sub>CE</sub> = 10.0 V, f = 10 MHz)	f <sub>T</sub>	50	–	MHz

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Pulse Test: Pulse Width ≤ 300 μs, D.C. ≤ 2%.

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## TYPICAL ELECTRICAL CHARACTERISTICS

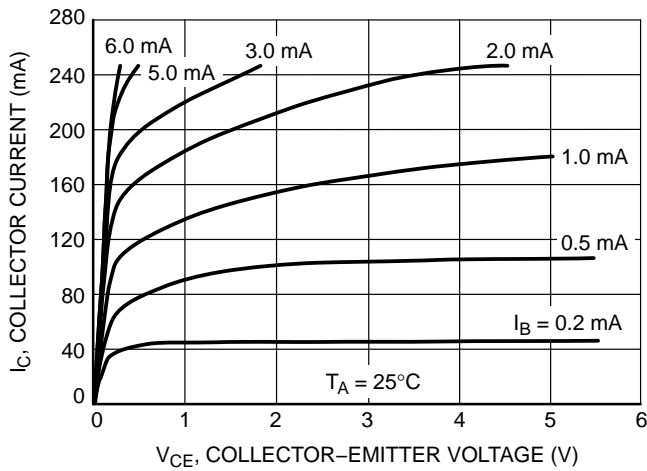


Figure 1. Collector Saturation Voltage

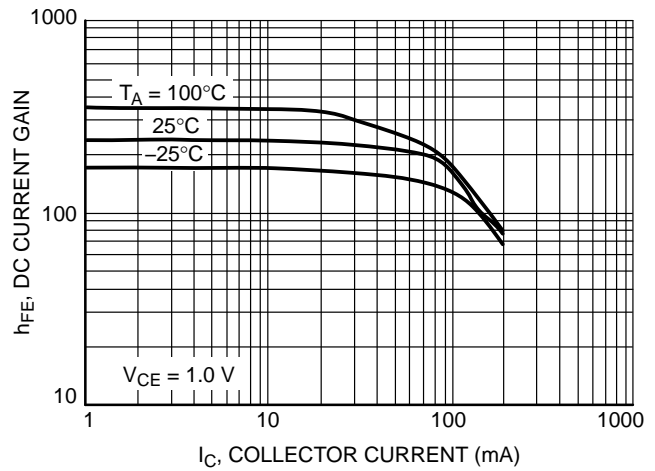


Figure 2. DC Current Gain

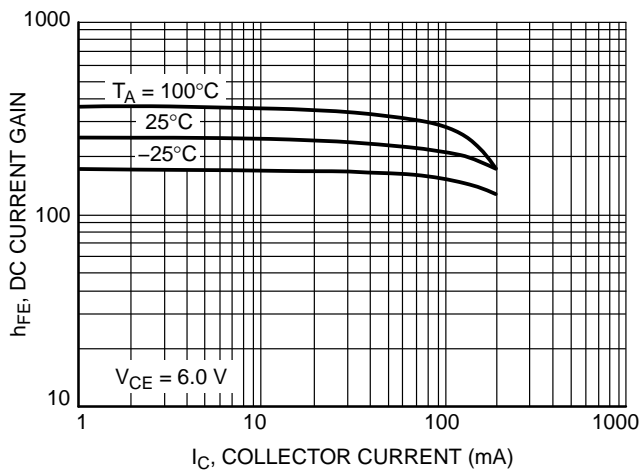


Figure 3. DC Current Gain

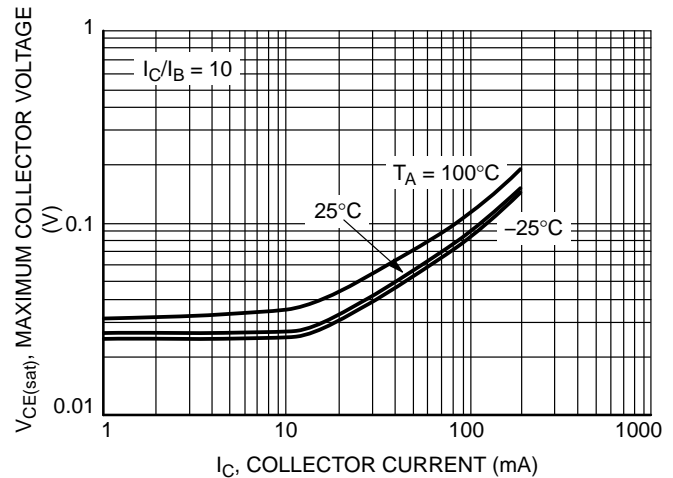


Figure 4.  $V_{CE(sat)}$  versus  $I_C$

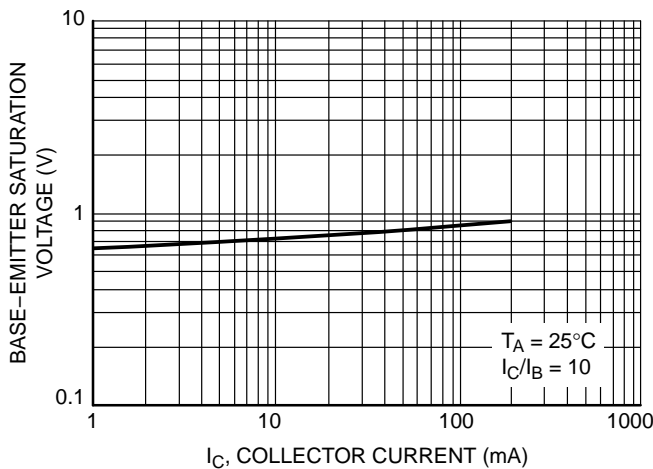


Figure 5.  $V_{BE(sat)}$  versus  $I_C$

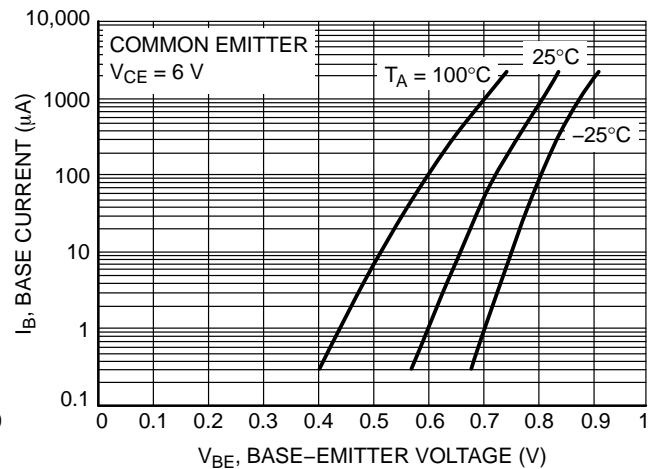


Figure 6. Base-Emitter Voltage

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## TYPICAL ELECTRICAL CHARACTERISTICS

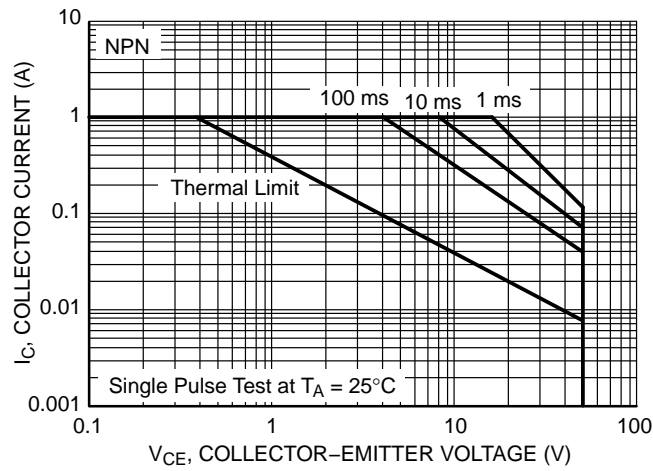
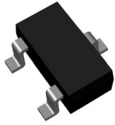
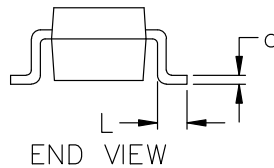
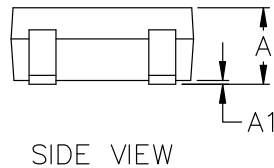
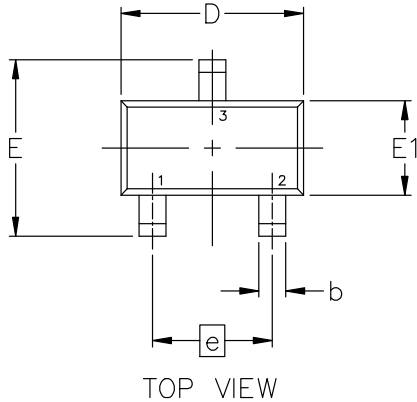


Figure 7. NPN Safe Operating Area



**SC-59-3 2.90x1.50x1.15, 1.90P**  
**CASE 318D**  
**ISSUE J**

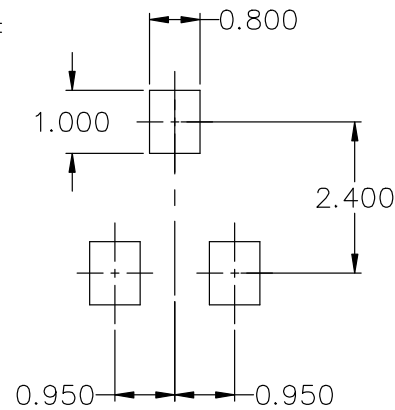
DATE 15 FEB 2024



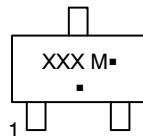
NOTES:

1. DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
2. ALL DIMENSION ARE IN MILLIMETERS.

DIM	MILLIMETERS		
	MIN.	NOM.	MAX.
A	1.00	1.15	1.30
A1	0.01	0.06	0.10
b	0.35	0.43	0.50
c	0.09	0.14	0.18
D	2.70	2.90	3.10
E	2.50	2.80	3.00
E1	1.30	1.50	1.70
e	1.90 BSC		
L	0.20	0.40	0.60



**GENERIC MARKING DIAGRAM\***



- XXX = Specific Device Code
- M = Date Code
- = Pb-Free Package\*

(\*Note: Microdot may be in either location)

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present. Some products may not follow the Generic Marking.

\* FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

- STYLE 1:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR
- STYLE 2:  
PIN 1. ANODE  
2. N.C.  
3. CATHODE
- STYLE 3:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE
- STYLE 4:  
PIN 1. CATHODE  
2. N.C.  
3. ANODE
- STYLE 5:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE
- STYLE 6:  
PIN 1. ANODE  
2. CATHODE  
3. ANODE/CATHODE

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<b>DESCRIPTION:</b>	<b>SC-59-3 2.90x1.50x1.15, 1.90P</b>	<b>PAGE 1 OF 1</b>

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